

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

MDP1922

FEATURES

- Static drain-source on-resistance: RDs(on) ≤8.4mΩ
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

 Be suitable for DC/DC converters and general purpose applications

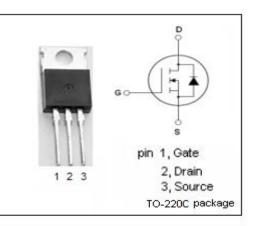
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

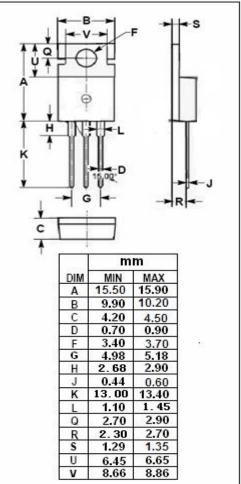
| SYMBOL | PARAMETER | VALUE | UNIT | | | | |
|------------------|---|------------------------------|------|--|--|--|--|
| V _{DSS} | Drain-Source Voltage | 100 | V | | | | |
| V _{GS} | Gate-Source Voltage | ±20 | V | | | | |
| I _D | Drain Current-Continuous | 97 | А | | | | |
| I _{DM} | Drain Current-Single Pulsed | 384 | A | | | | |
| P _D | Total Dissipation @T _c =25°C | ion @T _c =25℃ 157 | | | | | |
| Tj | Max. Operating Junction Temperature | 150 | °C | | | | |
| T _{stg} | Storage Temperature | -55~150 | °C | | | | |

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• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT | |
|-----------|---------------------------------------|-----|--------------|--|
| Rth(ch-c) | Channel-to-case thermal resistance | 0.8 | °C /W | |
| Rth(ch-a) | Channel-to-ambient thermal resistance | 62 | °C/W | |







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | МАХ | UNIT |
|---------------------|--------------------------------|--|-----|-----|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; ID =250 μ A | 100 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} ; ID =250 μ A | 2 | | 4 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D =50A | | | 8.4 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | $V_{GS}=\pm 20V; V_{DS}=0V$ | | | ±0.1 | μA |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =80V; V _{GS} = 0V | | | 1 | μA |
| V _{SD} | Diode forward voltage | Is=50A; V _{GS} = 0V | | | 1.2 | V |

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